

TECHNICAL DATA DATA SHEET 4608, REV.-

HERMETIC POWER SCHOTTKY RECTIFIER

(SINGLE / DUAL)

DESCRIPTION: A 45 VOLT, 7.5 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC LCC-3P PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ T_C = 25 °C UNLESS OTHERWISE SPECIFIED.

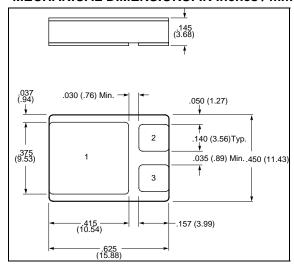
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	45	Volts
MAXIMUM DC OUTPUT CURRENT With Cathode Maintained (@ T_c =100 $^{\circ}$ C) (Single)	I _O	7.5	Amps
MAXIMUM DC OUTPUT CURRENT With Cathode Maintained (@ T_c =100 $^{\circ}$ C) (Common Cathode)	lo	15	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t = 8.3ms, Sine)	I _{FSM}	140	Amps
MAXIMUM JUNCTION CAPACITANCE (V _r =5V)	C _T	400	pF
MAXIMUM THERMAL RESISTANCE		1.21	°C/W
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE		-65 to + 150	°C

ELECTRICAL CHARACTERISTICS

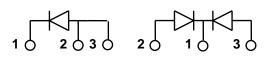
CHARACTERISTIC					
MAXIMUM FORWARD VOLTAGE DROP, Pulsed $(I_f = 7)$					
	T _J = 25 °C	V_{f}	0.64	Volts	
	T _J = 125 °C		0.59		
MAXIMUM REVERSE CURRENT (I _r @ 30 V PIV)					
	T _J = 25 °C	I_r	0.75	mA	
	T _J = 125 °C		35		

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MECHANICAL DIMENSIONS: IN Inches / mm





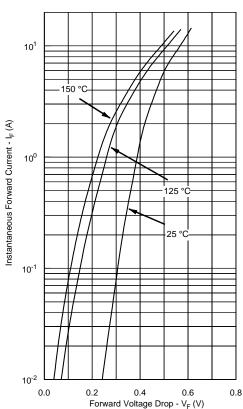


LCC-3P

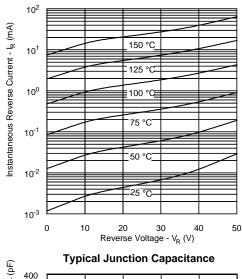
PINOUT TABLE

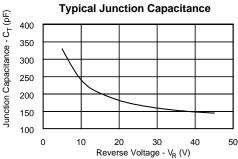
DEVICE TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
COMMON CATHODE	COMMON CATHODE	ANODE 1	ANODE 2





Typical Reverse Characteristics







TECHNICAL DATA

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